Amplifier Transistors

NPN Silicon

Features

• Pb-Free Package is Available*



Rating	Symbol	Value	Unit
Collector-Emitter Voltage BC546 BC547 BC548	V _{CEO}	65 45 30	Vdc
Collector-Base Voltage BC546 BC547 BC548	V _{СВО}	80 50 30	Vdc
Emitter-Base Voltage	V _{EBO}	6.0	Vdc
Collector Current – Continuous	I _C	100	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	Watt mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	–55 to +150	°C

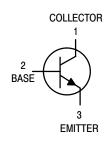
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

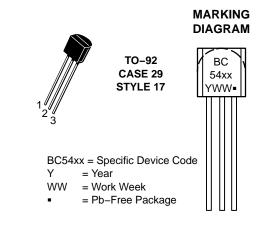
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{ heta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	83.3	°C/W



http://onsemi.com





ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

ELECTRICAL CHARACTERISTICS (T _A = Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		- ,		1 -21-	1	
Collector – Emitter Breakdown Voltage	BC546	V(DD) 050	65	l –	_	V
($I_C = 1.0 \text{ mA}, I_B = 0$)	BC547	$V_{(BR)CEO}$	45	_	_]
(0	BC548		30	_	_	
Collector – Base Breakdown Voltage	BC546	V _{(BR)CBO}	80	_	_	V
(I _C = 100 μAdc)	BC547	· (BK)CBO	50	_	_	•
()	BC548		30	_	_	
Emitter – Base Breakdown Voltage	BC546	V _{(BR)EBO}	6.0	_	_	V
$(I_E = 10 \mu A, I_C = 0)$	BC547	(5.1)250	6.0	_	_	
	BC548		6.0	_	-	
Collector Cutoff Current		I _{CES}				
$(V_{CE} = 70 \text{ V}, V_{BE} = 0)$	BC546		-	0.2	15	nA
$(V_{CE} = 50 \text{ V}, V_{BE} = 0)$	BC547		-	0.2	15	
$(V_{CE} = 35 \text{ V}, V_{BE} = 0)$	BC548		-	0.2	15	
$(V_{CE} = 30 \text{ V}, T_A = 125^{\circ}\text{C})$	BC546/547/548		-	-	4.0	μΑ
ON CHARACTERISTICS						
DC Current Gain		h _{FE}				_
$(I_C = 10 \mu A, V_{CE} = 5.0 V)$	BC547A		-	90	_	
	BC546B/547B/548B		-	150	_	
	BC548C		-	270	_	
$(I_C = 2.0 \text{ mA}, V_{CF} = 5.0 \text{ V})$	BC546		110	_	450	
(1C = 2.0 H/A, VCE = 3.0 V)	BC547		110	_	800	
	BC548		110	_	800	
	BC547A		110	180	220	
	BC546B/547B/548B		200	290	450	
	BC547C/BC548C		420	520	800	
$(I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC547A/548A		_	120	_	
	BC546B/547B/548B		-	180	_	
	BC548C		-	300	-	
Collector – Emitter Saturation Voltage		$V_{CE(sat)}$				V
$(I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA})$			_	0.09	0.25	
$(I_C = 100 \text{ mA}, I_B = 5.0 \text{ mA})$			_	0.2	0.6	
$(I_C = 10 \text{ mA}, I_B = \text{See Note 1})$			_	0.3	0.6	
Base – Emitter Saturation Voltage		$V_{BE(sat)}$	-	0.7	-	V
$(I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA})$						
Base – Emitter On Voltage		$V_{BE(on)}$				V
$(I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$			0.55	_	0.7	
$(I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V})$				_	0.77	
SMALL-SIGNAL CHARACTERISTICS						
Current - Gain - Bandwidth Product		f _T				MHz
$(I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 100 \text{ MHz})$	BC546		150	300	_	
	BC547		150	300	_	
0	BC548		150	300	-	
Output Capacitance		C_{obo}	-	1.7	4.5	pF
$(V_{CB} = 10 \text{ V}, I_{C} = 0, f = 1.0 \text{ MHz})$						_
Input Capacitance		C _{ibo}	-	10	-	pF
$(V_{EB} = 0.5 \text{ V}, I_{C} = 0, f = 1.0 \text{ MHz})$						
Small – Signal Current Gain	DOC 40	h _{fe}	405		500	-
$(I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 1.0 \text{ kHz})$	BC546		125	_	500	
	BC547/548		125	220	900	
	BC547A BC546B/547B/548B		125 240	220 330	260 500	
	BC546B/547B/546B BC547C/548C		450	600	900	
			700	000	550	I
Noise Figure	BC347C/346C	NF				ЧB
Noise Figure		NF	_	2 0	10	dB
Noise Figure (I _C = 0.2 mA, V _{CE} = 5.0 V, R _S = 2 k Ω , f = 1.0 kHz, Δ f = 200 Hz)	BC546 BC547	NF	- -	2.0 2.0	10 10	dB

^{1.} I_B is value for which I_C = 11 mA at V_{CE} = 1.0 V.

BC547/BC548

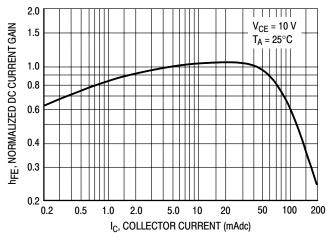


Figure 1. Normalized DC Current Gain

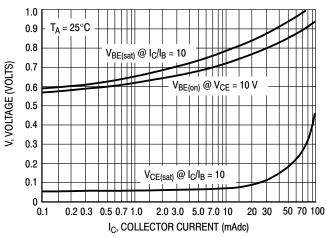


Figure 2. "Saturation" and "On" Voltages

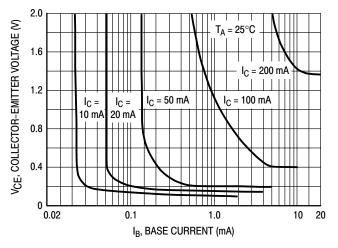


Figure 3. Collector Saturation Region

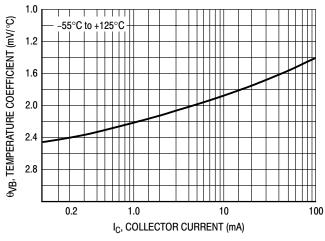


Figure 4. Base-Emitter Temperature Coefficient

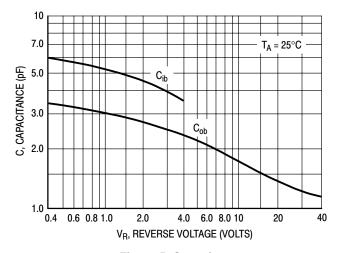


Figure 5. Capacitances

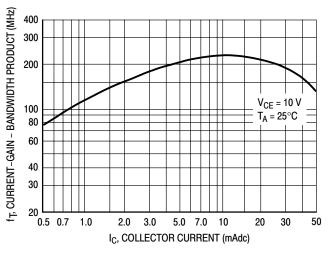


Figure 6. Current-Gain - Bandwidth Product

BC546

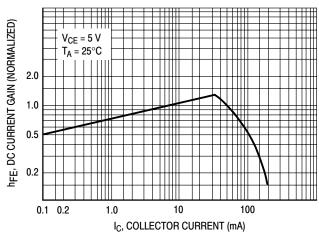


Figure 7. DC Current Gain

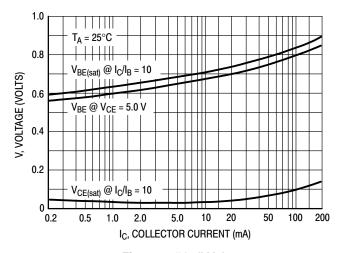


Figure 8. "On" Voltage

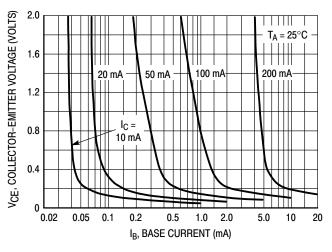


Figure 9. Collector Saturation Region

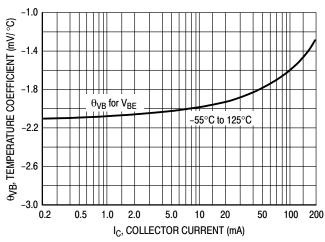


Figure 10. Base-Emitter Temperature Coefficient

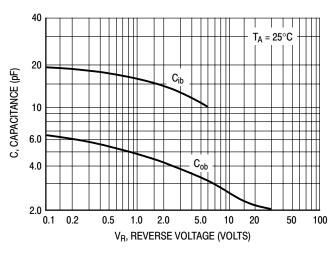


Figure 11. Capacitance

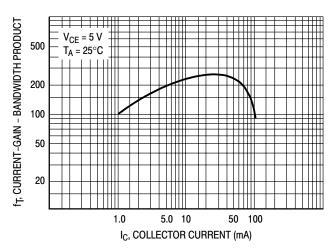


Figure 12. Current-Gain - Bandwidth Product

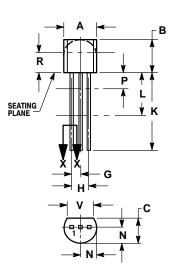
DEVICE ORDERING INFORMATION

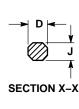
Device	Package	Shipping [†]	
BC546B		5000 Units / Bulk	
BC546BRL1		2000 Tape & Reel	
BC546BZL1		2000 Tape & Ammo Box	
BC547ARL		2000 Tape & Reel	
BC547ARL1		2000 Tape & Reel	
BC547AZL1		2000 Tape & Ammo Box	
BC547B	TO 00 (TO 000)	5000 Units / Bulk	
BC547BRL1	TO-92 (TO-226)	2000 Tape & Reel	
BC547BZL1		2000 Tape & Ammo Box	
BC547C		5000 Units / Bulk	
BC547CZL1		2000 Tape & Ammo Box	
BC548B		5000 Units / Bulk	
BC548BRL1		2000 Tape & Reel	
BC548BZL1			
BC548BZL1G	TO-92 (TO-226) (Pb-Free)	2000 Tape & Ammo Box	
BC548C	TO 00 (TO 000)	5000 Units / Bulk	
BC548CZL1	TO-92 (TO-226)	2000 Tape & Ammo Box	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AL**





NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
v	0.135		3 43	

STYLE 17:

PIN 1. COLLECTOR 2 BASE 3. EMITTER

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